

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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UTV8100B

100 Watts Pk, 28 Volt, Class AB UHF Television - Band IV & V

GENERAL DESCRIPTION

The UTV8100B is a COMMON EMITTER transistor capable of providing 100 Watt Peak, Class AB, RF Output Power over the band 470 - 860 MHz. The transistor includes double input and output prematching for full broadband capability. Gold Metalization and Diffused Ballasting are used to provide high reliability and supreme ruggedness.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 290 Watts

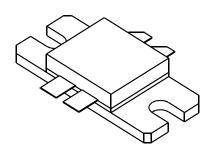
Maximum Voltage and Current

BVcboCollector to Emiter Voltage65 VoltsBVcooCollector to Emitter Voltage30 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current15 Amps

Maximum Temperatures

Storage Temperature $-40 \text{ to} + 150^{\circ}\text{C}$ Operating Junction Temperature $+200^{\circ}\text{C}$

CASE OUTLINE 55RT, STYLE 2



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
PldB Pin Po - ref Pg η	Power Out - 1 dB Compression Power Input Power Output - Linear Power Gain - Small Sig Efficiency	F =470 - 860 MHz Vcc = 28 Volts Icq = 300 mA (total)	100 25 8.5 55	9.5 58	14.0	Watts Watts Watts dB %
VSWR	Load Mismatch Tolerance	Pout = 25 Watts Pk	5:1			

^{*} European Test Method, Vision = -8 dB, Sideband = - 16 dB, Sound = - 7 dB

BVceo BVces	Collector to Emitter Breakdown Collector to Emitter Breakdown	Ic = 25 mA $Ic = 25 mA$ $Ic = 20 mA$	30 60			Volts Volts
BVebo Hfe	Emitter to Base Breakdown Current Gain	Ie = 30 mA Vce = 5 V, Ic = 1 A	3.5 20		120	Volts
Cob Rθjc	Output Capacitance - (each side)* Thermal Resistance	Vcb = 28V, F=1MHz Tc = 25 °C		44	0.6	pF °C/W

^{*} Not measureable due to internal prematch network

Issue December 1996

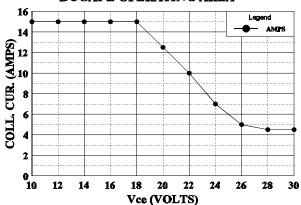
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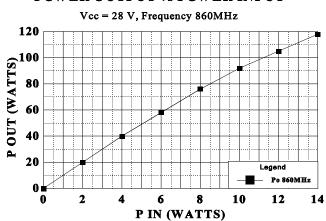


UTV8100B

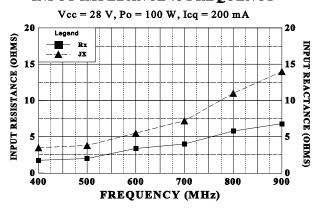
DC SAFE OPERATING AREA



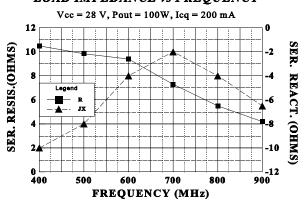
POWER OUTPUT vs POWER INPUT



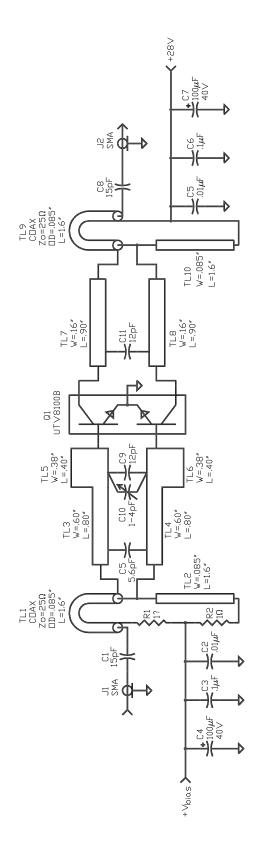
INPUT IMPEDANCE vs FREQUENCY



LOAD IMPEDANCE vs FREQUENCY



REVISIONS ZONE REV DESCRIPTION DATE APPROVED



Board type: PTFE/GLASS Board thickness: .031" Copper weight: 1oz

All dimensions are in inches.

CHz TECHNOLOGY

CAGE 0PJR2

DWG NO. UTV8100B REV Α

SCALE

SHEET